

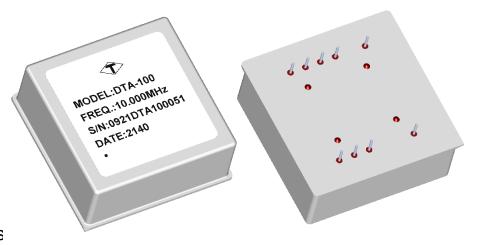
Low Power Atomic Oscillator DTA-100 Series

Feature:

- Low power consumption 150mW typical
- 1pps input and 1pps output for timing synchronization
- Discipline to 1ns RMS in phase and <10⁻¹² in frequency
- ullet 1 Second continuous phase measurement and report system, resolution \leq 1ns
- ToD(Time of Day)
- RS232 digital interface
- 10MHz HCMOS output
- Low phase noise, optional

Applications:

- GNSS Receivers
- Portable Radios
- IED Jamming System
- UAV
- Autonomous Sensor Networks



ELECTRICAL SPECIFICATIONS

1. RF OUTPUT

	Parameter		Min.	Тур.	Max.	Unit	Test Condition
1.1.	Frequency C	Output		10		MHz	
1.2.	Output Wave	eform		3.3V CMO	S		
1.3.	Load		10MΩ//10pF				
1.4.	Rise/Fall Time				10	nS	
1.5.	Output	V _{OL}			0.4	V	
	Level	V _{OH}	2.7			V	
1.6.	Duty Cycle		40		60	%	
1.7.	Frequency Stability over Temperature				±5x10 ⁻¹⁰		-10°C ~ 70°C Temperature Slope < 0.5°C/min.
1.8.	Frequency Stability				±4x10 ⁻¹⁰		



	Parameter	Min.	Тур.	Max.	Unit	Test Condition
1.9.	Frequency Accuracy			±5x10 ⁻¹¹		At shipment
1.10.	Daily Aging		±1x10 ⁻¹¹	±3x10 ⁻¹¹		After 30 days of continuous operation.
1.11.	Retrace			±5x10 ⁻¹⁰		48 hours off
				3x10 ⁻¹⁰		Tau=1sec
1.12.	Short Term(ADEV)			9.5x10 ⁻¹¹		Tau=10sec
				3x10 ⁻¹¹		Tau=100sec
				8x10 ⁻¹²		Tau=1000sec
1.13.	Frequency Control (Analog Tuning)		±2.2x10 ⁻⁸			Resolution : $1x10^{-11}$ Input : $0V \sim 2.5V$ into $100K\Omega$
1.14.	Frequency Control (Digital Tuning)		±1x10 ⁻⁸			Resolution: 1x10 ⁻¹²

2. 1pps Time Output

	Parameter	Min.	Тур.	Max.	Unit	Test Condition
2.1.	1pps	1			Hz	
2.2.	Output Amplitude	3.3V CMOS				
2.3.	Pulse Width		97.656	100	us	
2.4.	Rise/Fall Time			10	ns	
2.5.	Load	10MΩ//10pF				

3. 1pps Time Input

	Parameter	Min.	Тур.	Max.	Unit	Test Condition
3.1.	1pps	1Hz				
3.2.	Timing Edge	Rising edge				
3.3.	Low Level	0.5			V	
	High Level	2.5		3.3	V	
3.4.	Input Impedance	10MΩ//10pF				

4. Built-In Test Equipment (BITE) Output

	Parameter	Min.	Тур.	Max.	Unit	Test Condition
4.1.	Format	3.3V CMOS				
4.2.	Load Impedance	1ΜΩ				
4.3.	Logic	0 = Normal Operation 1 = Alarm				



5. Phase Noise (@10MHz)

	Parameter	Min.	Тур.	Max.	Unit	Test Condition
5.1.	1 Hz			-52	dBc/Hz	
5.2.	10 Hz			-90	dBc/Hz	
5.3.	100 Hz			-122	dBc/Hz	
5.4.	1 KHz			-140	dBc/Hz	
5.5.	10 KHz			-150	dBc/Hz	
5.6.	100 KHz			-152	dBc/Hz	
5.7.	1MHz			-152	dBc/Hz	

6. Supply Voltage

	Parameter	Min.	Тур.	Max.	Unit	Test Condition
6.1.	Supply Voltage	3.2	3.3	3.4	Vdc	
6.2.	Steady Power		150	170	mW	-10°C ~ 70°C
6.3.	Warm up Power			170	mW	
6.4.	Warm up Time			150	Second	

7. Digital Communication

	Parameter	Reference Std.	Test Condition
7.1.	Protocol	RS232	
7.2.	Logic Level	3.3V CMOS	
7.3.	Baud Rate	57600	
7.4.	Number of Data Bits	8	
7.5.	Number of Stop Bits	1	
7.6.	Parity	none	

8. Environmental

	Parameter	Test Condition	Reference Std.
8.1.	Storage Temperature	-40°C ~ 85°C	Non-operating
8.2.	Mechanical Shock	>30G, 11ms Half Sine	MIL-STD-202
8.3.	Vibration	7G rms, maintain lock	MIL-STD-810
8.4.	Humidity	0-95%, RH	
8.5.	Magnetic Sensitivity	<±1x10 ⁻¹⁰ /1 Gauss	Up to 2 Gauss

Table 1: ORDERING INFORMATION

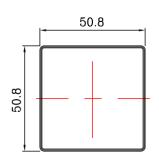
DTA-100 Series	FootPrint			
	Standard (A)	Optional (B)		
Ordering Information	DTA-100-A-R	DTA-100-B-R		



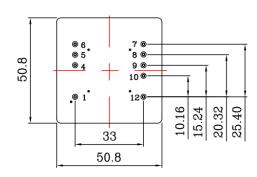
OUTLINE DRAWING

Standard Footprint:

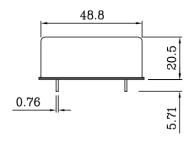




[BOTTOM VIEW]



[SIDE VIEW]

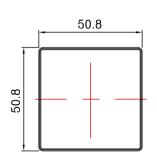


Unit: mm

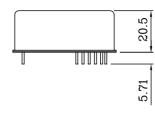
PIN#	FUNCTION
1	Tune
4	BITE
5	TX
6	RX
7	VCC
8	GND
9	1pps In
10	1pps Out
12	10MHz Out

Optional Footprint:

[TOP VIEW]



]	SIDE	VIEW]	



Unit: mm

[BOTTOM VIEW]	
6.07	P3.048*4=12.17
PIN 8 PIN 9 PIN 3 PIN 10	
PI <u>N 2</u>	23.01
40.64	PIN 5

PIN#	FUNCTION
1	NC
2	GND
3	RF Output
4	GND
5	+3.3V
6	Lock 0:Lock 1:Unlock
7	TX
8	RX
9	1pps In
10	1pps Out